NSN 5961-01-324-0663

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-324-0663 **Inclosure Material:** Glass **Overall Length:** 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.107 inches **Function For Which Designed:** Rectifier Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage and 100.0 working peak reverse voltage and 100.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute and 20.00 amperes source cutoff current absolute and 35.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No